## NPN 0.7A 80V Middle Power Transistor

Parameter	Value
$V_{\sf CEO}$	80V
I <sub>C</sub>	0.7A

## Features

1) Suitable for Middle Power Driver

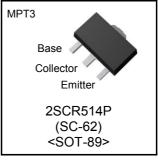
2) Complementary PNP Types: 2SAR514P

3) Low V<sub>CE(sat)</sub>

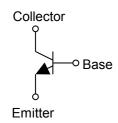
 $V_{CE(sat)}$ =0.30V(Max.)  $(I_C/I_B = 300 \text{mA}/15 \text{mA})$ 

4) Lead Free/RoHS Compliant.

Outline



#### •Inner circuit



## Applications

Motor driver, LED driver Power supply

## Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SCR514P	MPT3	4540	T100	180	12	1,000	ND

## ● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		$V_{CBO}$	80	V
Collector-emitter voltage		$V_{CEO}$	80	V
Emitter-base voltage	pase voltage V <sub>EBO</sub>		6	V
Collector current	DC	I <sub>C</sub>	0.7	А
	Pulsed	I <sub>CP</sub> *1	1.4	Α
Power dissipation		P <sub>D</sub> *2	0.5	W
		P <sub>D</sub> *3	2.0	W
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	−55 to +150	°C

<sup>\*1</sup> Pw=10ms, single pulse

<sup>\*2</sup> Each terminal mounted on a reference land

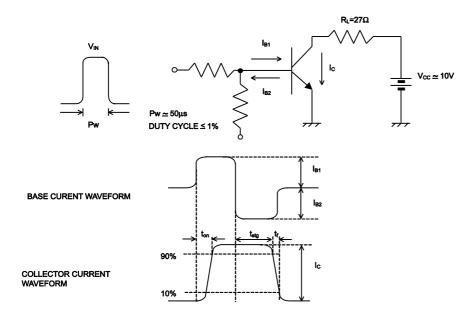
<sup>\*3</sup> Mounted on a ceramic board (40×40×0.7mm)

## ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 1mA	80	-	-	V
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> = 100μA	80	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 100μA	6	ı	ı	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 80V	ı	ı	1	μА
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 4V	ı	-	1	μА
Collector-emitter saturation voltage	V <sub>CE(sat)</sub> *1	I <sub>C</sub> = 300mA, I <sub>B</sub> = 15mA	-	0.10	0.30	V
DC current gain	h <sub>FE</sub>	$V_{CE} = 3V, I_{C} = 100mA$	120	-	390	-
Transition frequency	f <sub>⊤</sub>	$V_{CE} = 10V, I_{E} = -200 \text{mA}$ f=100MH <sub>Z</sub>	-	320	-	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = 10V$ , $I_E = 0A$ f = 1MHz	1	6	-	pF
Turn-on time	t <sub>on</sub> *2	I <sub>C</sub> =0.35A	ı	50	ı	ns
Storage time	t <sub>stg</sub> *2	I <sub>B1</sub> =35mA I <sub>B2</sub> = –35mA	ı	650	ı	ns
Fall time	t <sub>f</sub> *2	V <sub>cc</sub> ≃10V	-	100	-	ns

<sup>\*1</sup> Pulsed

## •Switching time test circuit



<sup>\*2</sup> See switching time test circuit

## ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

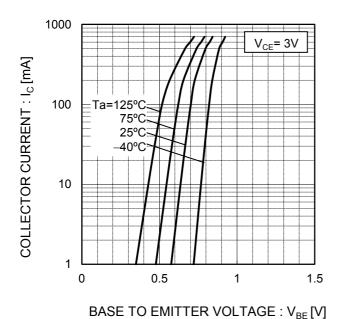
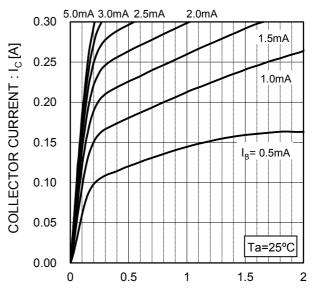


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V<sub>CE</sub>[V]

Fig.3 DC Current Gain vs. Collector Current(I)

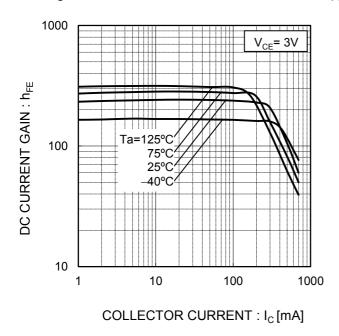
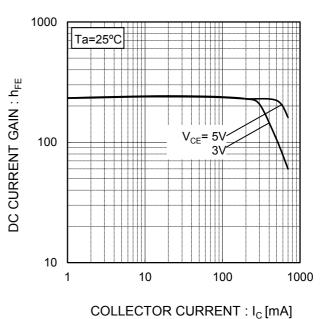
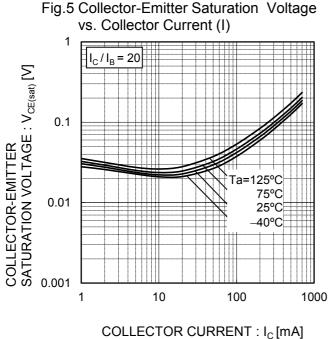


Fig.4 DC current gain vs. output current (II)



### ●Electrical characteristic curves(Ta = 25°C)



vs. Collector Current (II) SATURATION VOLTAGE: V<sub>CE(sat)</sub> [V]
10
10  $I_{\rm C} / I_{\rm B} = 50$ COLLECTOR-EMITTER 20 10 100 1000

COLLECTOR CURRENT : I<sub>C</sub> [mA]

Fig.6 Collector-Emitter Saturation Voltage

Fig.7 Base-Emitter Saturation Voltage vs. Collector Current 10 BASE-EMITTER SATURATION VOLTAGE : V<sub>BE(sat)</sub> [V] Ta= -40°C 25°C 75°C 125°C  $I_{\rm C}/I_{\rm B} = 20$ Pulsed 0.1 1 10 100 1000 COLLECTOR CURRENT : I<sub>C</sub> [mA]

Fig.8 Gain Bandwidth Product vs. Emitter Current 1000 Ta=25°C TRANSITION FREQUENCY : f<sub>T</sub> [MHz] V<sub>CE</sub>= 10V 100 10 -10 -100 -1000

EMITTER CURRENT : I<sub>E</sub> [mA]

## ●Electrical characteristic curves(Ta = 25°C)

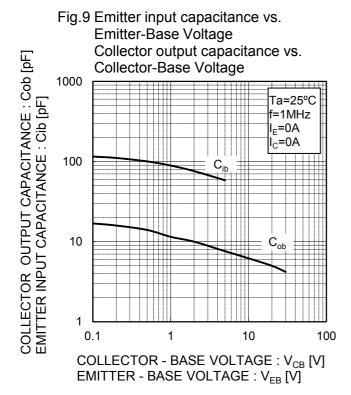
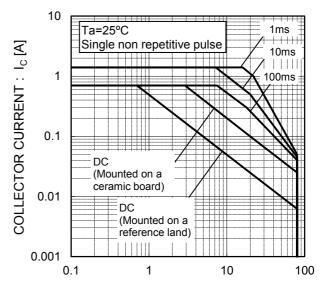
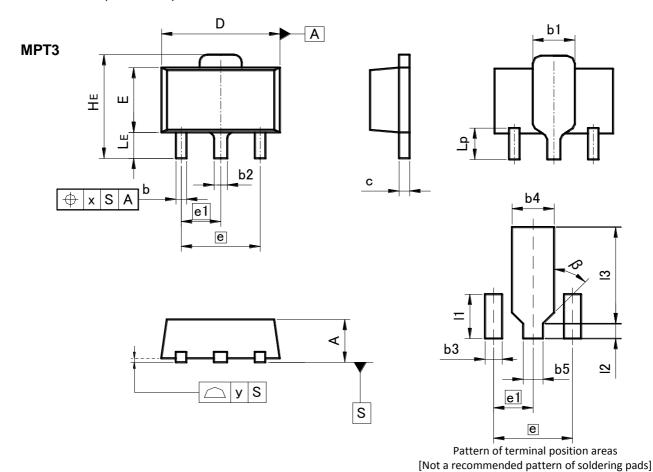


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE: V<sub>CE</sub>[V]

## ●Dimensions (Unit: mm)



DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
Е	2.40	2.70	0.094	0.106	
е	3.00		0.118		
e1	1.50		0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х	_	0.15	-	0.006	
У	_	0.10	-	0.004	

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
b3	-	0.65	-	0.026	
b4	-	1.70	_	0.067	
b5	-	0.75	_	0.030	
11	ı	1.71	1	0.067	
12	ı	0.58	1	0.023	
13	-	3.72	-	0.146	
β	45°		45°		

Dimension in mm / inches

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